Role of Advanced Electron Microscopy in Unraveling Complex Microstructure in Nanostructured Thermoelectric Materials

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Thermoelectric (TE) materials can enable direct conversion between thermal and electrical energies and can impact waster heat recovery [1]. The conversion efficiency is determined by dimensionless figure of merit, $ZT = S^2 \sigma T/\kappa$, where S is the Seebeck coefficient, σ is the electrical conductivity, κ is the total thermal conductivity, and T is the absolute temperature. PbTe, a simple cubic rock-salt structure, has been studied for decades due to their promising band structure and high thermoelectric performance. Moreover, due to the simple crystal structure, faceted nano-precipitates can be easily constructed via supersaturated doping/alloying. Such highly strained nanostructure can greatly enhance phonon scattering and suppress the lattice thermal conductivity [2]. Here we have systematically characterized nanostructures in PbTe based materials, which lead to significantly enhanced thermoelectric properties [3].

Figure 1(a) shows a typical annular bright field (ABF) STEM image of Pb_{0.98}Ga_{0.02}Te-5%GeTe, where a significant amount of faceted second phase ranging from ~20 to 150 nm with brighter contrast is seen inside of the grain of the PbTe matrix. Moreover, numerous dislocations are located around the precipitates. From the energy dispersive spectroscopy (EDS) mapping (**Figure 1(b)**) of a selected area in (a), the precipitates are rich in Ga and deficient in Pb.

To reveal more crystallographic information and orientation relationship between the precipitates and matrix, conventional and high-resolution TEM analyses were also applied. **Figure 1(c)** shows a middle-magnification TEM image of one such precipitate embedded in the matrix. Translational Moiré fringes are present due to lattice misfit between the two phases. According to the zoomed-in view of a part of the interface in **Figure 1(d)**, the lattice fringes between the two phases are coherent (endotaxy). The corresponding selected area electron diffraction (SAED) is shown in **Figure 1(e)**, where the bright diffraction spots belong to the rock-salt PbTe phase along the [111] direction. 6 satellite spots are observed around every bright spot, with the brightest ones originating from Ga₂Te₃ along [111] zone axis. The presence of all other weaker satellite spots as well as the translational Morié fringes come from double diffraction.

As a result, the nanoscale Ga_2Te_3 precipitates, dislocations and point defects leads to intensified phonon scattering and significant suppressed lattice thermal conductivity of 1.13 Wm⁻¹K⁻¹, nearly 34% reduction compared to that of $Pb_{0.98}Ga_{0.02}Te$ (1.72 Wm⁻¹K⁻¹) at 300 K [3, 4].



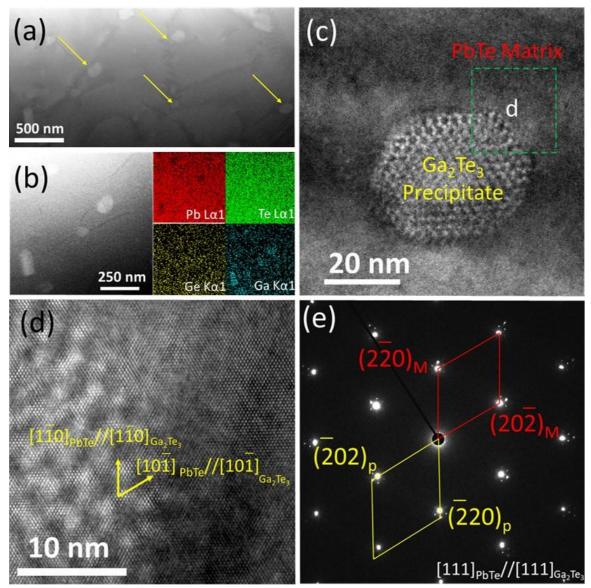


Figure 1. S/TEM analyses of Pb0.98Ga0.02Te-5%GeTe. (a) Annular bright field STEM image. Decent amount of precipitates (indicated by yellow arrows) with brighter contrast are embedded in the PbTe matrix. The size of the precipitates is ~20-60 nm. (b) Zoom-in view of (a) along with EDS mapping. The precipitates are Ga-rich and Pb-deficient. (c) Typical TEM image of one precipitate embedded in the matrix. (d) Zoomed-in high-resolution TEM image of boxed area in (c), revealing a coherent phase boundary. (e) Corresponding selected area electron diffraction pattern (SAED) of (c) along the [111] direction of the PbTe matrix. The bright spots (labeled in red) belong to the PbTe phase, while the brightest satellite spots (labeled in yellow) were indexed to the Ga2Te3 phase (space group: F 43m) along the [111] direction. Other satellite spots are generated due to double diffraction. [3]

References

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